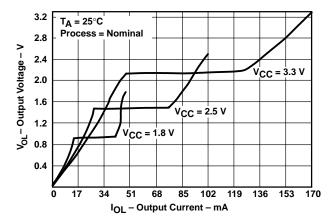
- Member of the Texas Instruments
 Widebus™ Family
- DOC™ (Dynamic Output Control) Circuit Dynamically Changes Output Impedance, Resulting in Noise Reduction Without Speed Degradation
- Dynamic Drive Capability Is Equivalent to Standard Outputs With I_{OH} and I_{OL} of ±24 mA at 2.5-V V_{CC}
- Overvoltage-Tolerant Inputs/Outputs Allow Mixed-Voltage-Mode Data Communications
- I_{off} Supports Partial-Power-Down Mode Operation
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

description

A Dynamic Output Control (DOC^{TM}) circuit is implemented, which, during the transition, initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figure 1 shows typical V_{OL} vs I_{OL} and V_{OH} vs I_{OH} curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DOC circuit provides a maximum dynamic drive that is equivalent to a high-drive standard-output device. For more information, refer to TI application reports AVC Logic Family Technology and Applications, literature number SCEA006, and Dynamic Output Control (DOC^{TM}) Circuitry Technology and Applications, literature number SCEA009.



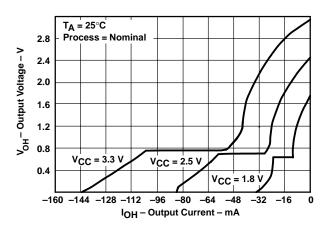


Figure 1. Output Voltage vs Output Current

This 18-bit universal bus driver is operational at 1.2-V to 3.6-V V_{CC} , but is designed specifically for 1.65-V to 3.6-V V_{CC} operation.

Data flow from A to Y is controlled by the output-enable (\overline{OE}) input. The device operates in the transparent mode when the latch-enable (LE) input is high. The A data is latched if the clock (CLK) input is held at a high or low logic level. If LE is low, the A data is stored in the latch/flip-flop on the low-to-high transition of CLK. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

DOC and Widebus are trademarks of Texas Instruments.



terminal assignments

DGG OR DGV PACKAGE (TOP VIEW)

	1		_		
NC	d	1	\cup	56	GND
NC		2		55	NC
Y1		3		54] A1
GND	D	4		53	GND
Y2		5		52] A2
Y3		6		51] A3
V_{CC}		7		50	Vcc
Y4		8		49] A4
Y5		9		48] A5
Y6		10		47] A6
GND	Ц	11		46	GND
Y7	Ц	12		45] A7
Y8	Ц	13		44	8A [
Y9	Ц	14		43	A9
Y10		15		42	A10
Y11		16		41	A11
Y12	Ц	17		40	A12
GND	Ц	18		39	GND
Y13	Ц	19		38] A13
Y14		20		37	A14
Y15	Ц	21		36	A15
V_{CC}	Ц	22		35	Vcc
Y16	Ц	23		34	A16
Y17	Ц	24		33	A17
GND		25		32	GND
Y18	\Box	26		31	A18
OE		27		30	CLK
LE	\Box	28		29	GND

NC - No internal connection

ORDERING INFORMATION

TA	PACKAGE [†]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	TSSOP – DGG	Tape and reel	SN74AVC16835DGGR	AVC16835
-40 C to 65 C	TVSOP - DGV	Tape and reel	SN74AVC16835DGVR	CVA835

[†]Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

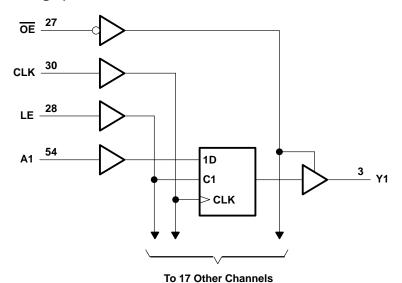


FUNCTION TABLE (each universal bus driver)

	INF	PUTS		OUTPUT
OE	LE	CLK	Υ	
Н	Χ	Х	Χ	Z
L	Н	Χ	L	L
L	Н	Χ	Н	Н
L	L	\uparrow	L	L
L	L	\uparrow	Н	Н
L	L	L or H	Χ	Y ₀ †

[†]Output level before the indicated steady-state input conditions were established, provided that CLK is high before LE goes low

logic diagram (positive logic)





SN74AVC16835 18-BIT UNIVERSAL BUS DRIVER WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance or power-off state, VO	
(see Note 1)	–0.5 V to 4.6 V
Voltage range applied to any output in the high or low state, VO	
(see Notes 1 and 2)	$0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I _{IK} (V _I < 0)	
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, IO	±50 mA
Continuous current through each V _{CC} or GND	±100 mA
Package thermal impedance, θ _{JA} (see Note 3): DGG package	64°C/W
DGV package	48°C/W
Storage temperature range, T _{stq}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

- 2. The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.



recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
Vaa	Cupply voltage	Operating	1.4	3.6	V	
VCC	Supply voltage	Data retention only	1.2		V	
		V _{CC} = 1.2 V	VCC			
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	0.65 × V _{CC}			
V_{IH}	High-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7			
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2			
		V _{CC} = 1.2 V		GND		
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		$0.35 \times V_{CC}$		
V_{IL}	Low-level input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		0.8		
٧ _I	Input voltage		0	3.6	V	
۷o	Output voltage	Active state	0	VCC	V	
٧O	Output voltage	3-state	0	3.6	V	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		-2		
lavia	Static high-level output current [†]	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		-4	mA	
lohs	Static high-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-8	IIIA	
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		-12		
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2		
lols	Static low-level output current [†]	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		4	mA	
	Static low-level output current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		8	mA	
		V _{CC} = 3 V to 3.6 V		12		
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$		5	ns/V	
TA	Operating free-air temperature		-40	85	°C	

[†] Dynamic drive capability is equivalent to standard outputs with I_{OH} and I_{OL} of ±24 mA at 2.5-V V_{CC}. See Figure 1 for V_{OL} vs I_{OL} and V_{OH} vs I_{OH} characteristics. Refer to TI application reports *AVC Logic Family Technology and Applications*, literature number **SCEA006**, and *Dynamic Output Control (DOC™) Circuitry Technology and Applications*, literature number **SCEA009**.

NOTE 4: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to TI application report *Implications* of Slow or Floating CMOS Inputs, literature number SCBA004.



electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	Vcc	MIN	TYP [†]	MAX	UNIT	
		$I_{OHS} = -100 \mu A$,		1.4 V to 3.6 V	V _{CC} -0.	2			
		$I_{OHS} = -2 \text{ mA},$	V _{IH} = 0.91 V	1.4 V	1.05				
Vон		$I_{OHS} = -4 \text{ mA},$	V _{IH} = 1.07 V	1.65 V	1.2			V	
		$I_{OHS} = -8 \text{ mA},$	V _{IH} = 1.7 V	2.3 V	1.75				
		$I_{OHS} = -12 \text{ mA},$	V _{IH} = 2 V	3 V	2.3				
		$I_{OLS} = 100 \mu A$		1.4 V to 3.6 V			0.2		
		$I_{OLS} = 2 \text{ mA},$	V _{IL} = 0.49 V	1.4 V			0.4		
VOL		$I_{OLS} = 4 \text{ mA},$	$V_{IL} = 0.57 V$	1.65 V			0.45	V	
		$I_{OLS} = 8 \text{ mA},$	$V_{IL} = 0.7 V$	2.3 V			0.55		
		$I_{OLS} = 12 \text{ mA},$	$V_{IL} = 0.8 V$	3 V			0.7		
П		$V_I = V_{CC}$ or GND		3.6 V			±2.5	μΑ	
I _{off}		V_I or $V_O = 3.6 V$		0			±10	μΑ	
loz		$V_O = V_{CC}$ or GND,	OE = V _{CC}	3.6 V			±10	μΑ	
ICC		$V_I = V_{CC}$ or GND,	IO = 0	3.6 V			40	μΑ	
	CLK input	V _I = V _{CC} or GND		2.5 V		4			
	OLK Input	Al = ACC or QUAD		3.3 V		4			
Ci	Control inputs	V _I = V _{CC} or GND		2.5 V		4		pF	
^C	Control inputs	AL = ACC OLGIAD		3.3 V		4		ρı	
Data inputs		V _I = V _{CC} or GND		2.5 V		2.5			
		AL = ACC OLGIAD		3.3 V		2.5			
C Outputs	Vo = Voo or GND		2.5 V		6.5		ςE.		
Co	Outputs	$V_O = V_{CC}$ or GND		3.3 V		6.5		pF	

[†] Typical values are measured at $T_A = 25$ °C.

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)

			V _{CC} = 1.2 V		V _{CC} = 1.5 V ± 0.1 V		V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		UNIT	
				MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock freq	luency							150		150		150	MHz
	Pulse LE high							3.3		3.3		3.3		ns
t _W	duration	CLK high or low						3.3		3.3		3.3		115
		Data before CLK↑		1		0.9		0.7		0.7		0.7		
t _{su}	Setup time	Data	CLK high	1.7		1.6		1.2		0.8		0.8		ns
	unio	before LE↓	CLK low	2		0.9		0.7		0.5		0.5		
		Data after CL	. K ↑	1.5		1.3		1		0.9		1.3		
t _h	Hold th time	Data	CLK high	3.2		2.4		2		1.7		1.6		ns
		after LE↓	CLK low	2.8		2.1		1.7		1.5		1.4		

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switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 2 through 5)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.2 V	V _{CC} =		V _{CC} = ± 0.1		V _{CC} =		V _{CC} =		UNIT
	(1141 01)	(001101)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}						150		150		150		MHz
	Α		4.5	1.2	6.2	1.3	5.5	1	3.1	0.9	2.5	
^t pd	LE	Y	6.2	1.6	9.4	1.3	7.2	1.1	4.7	0.9	3.8	ns
	CLK		5.2	1.6	7.8	1.5	6	1	3.7	0.8	3.1	
t _{en}	ŌE	Υ	7.1	2.4	10.2	2.2	8.8	1.5	6.7	1.2	6.2	ns
t _{dis}	ŌĒ	Y	6.9	2.2	10.3	2	8.4	1.2	5.3	1.1	5.3	ns

switching characteristics, $T_A = 0$ °C to 85°C, $C_L = 0$ pF[†]

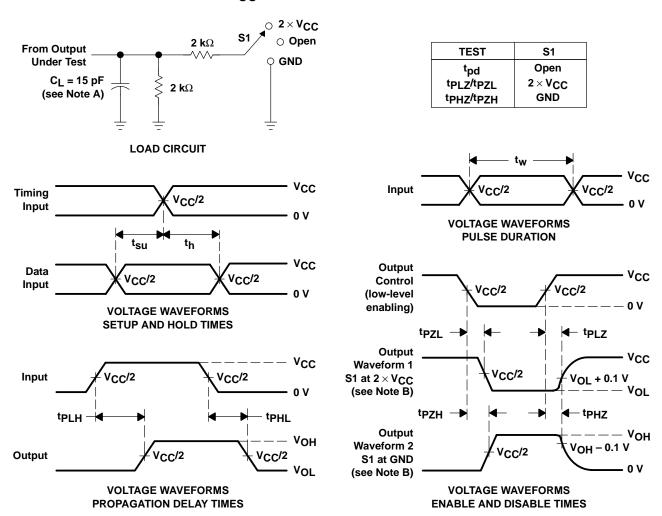
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1	UNIT	
	(1141 01)	(6611 61)	MIN	MAX	
• .	А	V	0.6	1.3	no
ιpd	CLK	Ţ	0.7	1.5	ns

[†] Texas Instruments SPICE simulation data

operating characteristics, T_A = 25°C

PARAMETER			TEST CONDITION)NG	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT	
PARAMETER		TEST CONDITIO	JNS	TYP	TYP	TYP	UNIT		
	Power dissipation	Outputs enabled	C: 0 f 10	N/I I	45	48	52	рF	
Cpd	capacitance	Outputs disabled	$C_L = 0, \qquad f = 10$	IVITZ	23	25	28	рr	

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.2 \text{ V}$ AND 1.5 V \pm 0.1 V



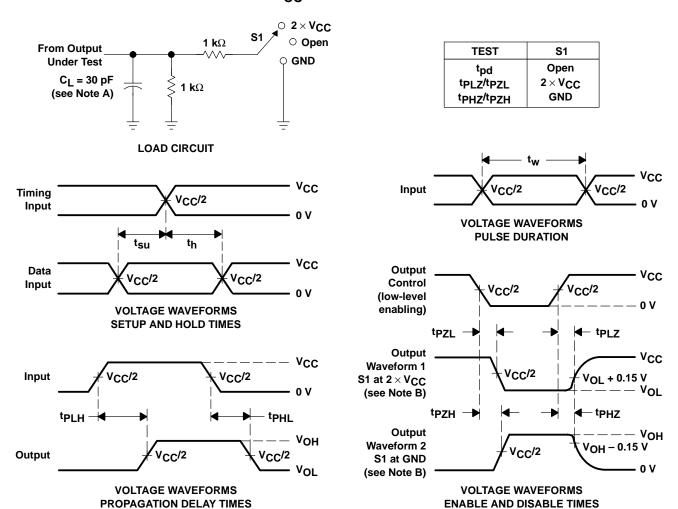
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns. $t_f \leq 2$ ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



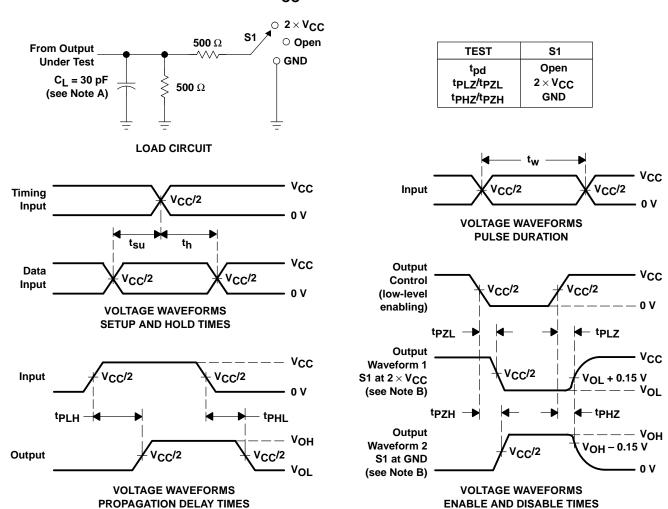
PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns, $t_f \leq 2$ ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLZ and tpHZ are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

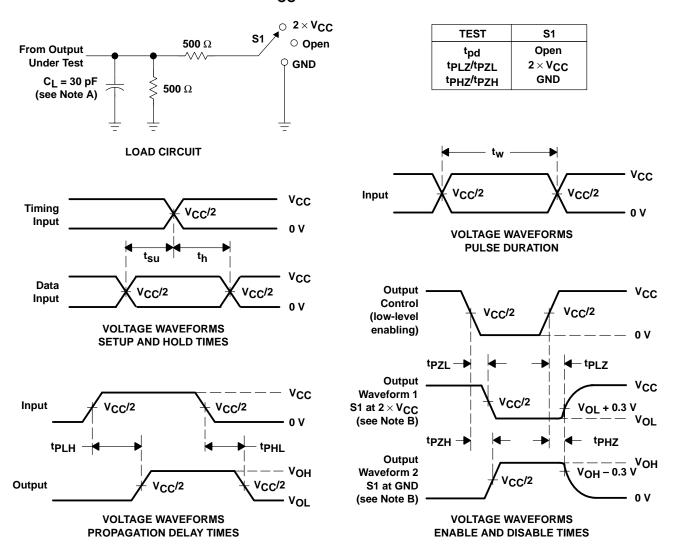


- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLZ and tpHZ are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 4. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION V_{CC} = 3.3 V \pm 0.3 V



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq 2$ ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. tpLH and tpHL are the same as tpd.

Figure 5. Load Circuit and Voltage Waveforms







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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74AVC16835DGGRE4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AVC16835DGGRG4	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AVC16835DGVRE4	ACTIVE	TVSOP	DGV	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AVC16835DGVRG4	ACTIVE	TVSOP	DGV	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC16835DGGR	ACTIVE	TSSOP	DGG	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC16835DGVR	ACTIVE	TVSOP	DGV	56	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

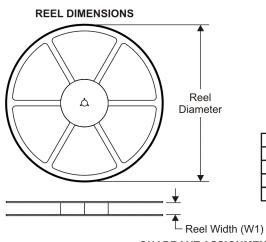
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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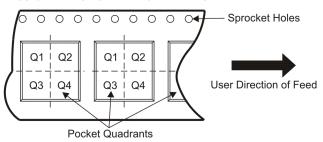
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

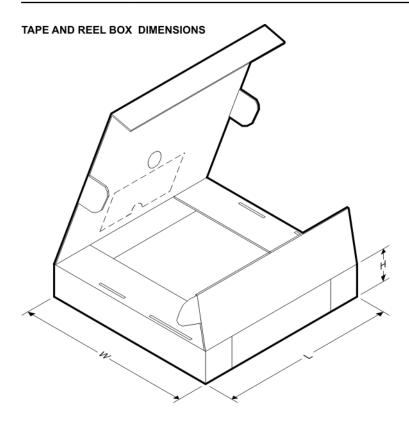
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC16835DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
SN74AVC16835DGVR	TVSOP	DGV	56	2000	330.0	24.4	6.8	11.7	1.6	12.0	24.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC16835DGGR	TSSOP	DGG	56	2000	346.0	346.0	41.0
SN74AVC16835DGVR	TVSOP	DGV	56	2000	346.0	346.0	41.0

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

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